MC14051B, MC14052B, MC14053B

Analog Multiplexers/Demultiplexers

The MC14051B, MC14052B, and MC14053B analog multiplexers are digitally–controlled analog switches. The MC14051B effectively implements an SP8T solid state switch, the MC14052B a DP4T, and the MC14053B a Triple SPDT. All three devices feature low ON impedance and very low OFF leakage current. Control of analog signals up to the complete supply voltage range can be achieved.

- Triple Diode Protection on Control Inputs
- Switch Function is Break Before Make
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Analog Voltage Range ($V_{DD} – V_{EE}$) = 3.0 to 18 V
  Note: V_{EE} must be $\leq V_{SS}$
- Linearized Transfer Characteristics
- Low–noise – 12 nV/$\sqrt{\text{Cycle}}$, f ≥ 1.0 kHz Typical
- Pin–for–Pin Replacement for CD4051, CD4052, and CD4053
- For 4PDT Switch, See MC14551B
- For Lower R_{ON}, Use the HC4051, HC4052, or HC4053 High–Speed CMOS Devices

MAXIMUM RATINGS (Note 1.)

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage (Referenced to V_{EE}, $V_{SS} \geq V_{EE}$)	–0.5 to +18.0	V
V_{in}, V_{out}	Input or Output Voltage Range (DC or Transient) (Referenced to V_{SS} for Control Inputs and V_{EE} for Switch I/O)	–0.5 to V_{DD} + 0.5	V
I_{in}	Input Current (DC or Transient) per Control Pin	±10	mA
I_{SW}	Switch Through Current	±25	mA
P_D	Power Dissipation, per Package (Note 2.)	500	mW
T_A	Ambient Temperature Range	–55 to +125	°C
T_{stg}	Storage Temperature Range	–65 to +150	°C
T_L	Lead Temperature (8–Second Soldering)	260	°C

1. Maximum Ratings are those values beyond which damage to the device may occur.
2. Temperature Derating:
   Plastic “P and D/DW” Packages: – 7.0 mW/°C From 65°C To 125°C

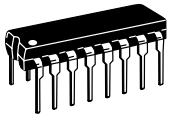
This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in}$ or $V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS}, V_{EE} or V_{DD}). Unused outputs must be left open.

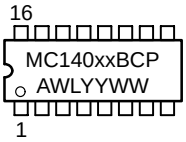
ON Semiconductor

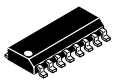
http://onsemi.com

MARKING DIAGRAMS

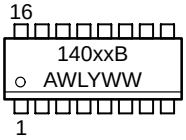


PDIP–16
P SUFFIX
CASE 648

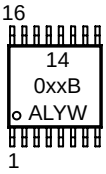


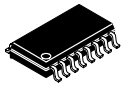


SOIC–16
D SUFFIX
CASE 751B

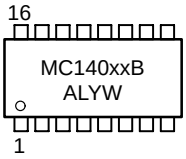


TSSOP–16
DT SUFFIX
CASE 948F





SOEIAJ–16
F SUFFIX
CASE 966

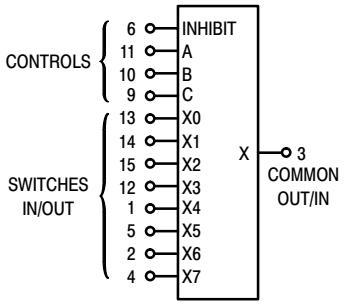


xx	= Specific Device Code
A	= Assembly Location
WL, L	= Wafer Lot
YY, Y	= Year
WW, W	= Work Week

ORDERING INFORMATION

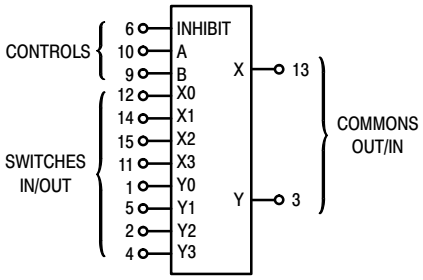
See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

MC14051B
8–Channel Analog Multiplexer/Demultiplexer



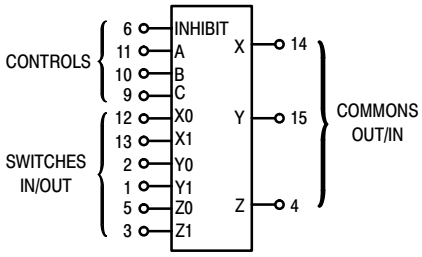
V_{DD} = PIN 16
V_{SS} = PIN 8
V_{EE} = PIN 7

MC14052B
Dual 4–Channel Analog Multiplexer/Demultiplexer



V_{DD} = PIN 16
V_{SS} = PIN 8
V_{EE} = PIN 7

MC14053B
Triple 2–Channel Analog Multiplexer/Demultiplexer

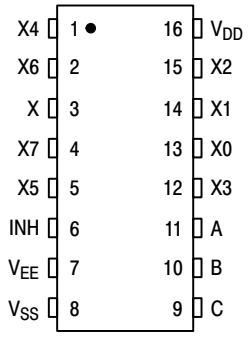


V_{DD} = PIN 16
V_{SS} = PIN 8
V_{EE} = PIN 7

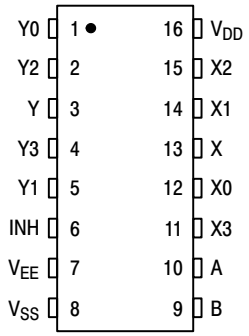
Note: Control Inputs referenced to V_{SS}, Analog Inputs and Outputs reference to V_{EE}. V_{EE} must be ≤ V_{SS}.

PIN ASSIGMENT

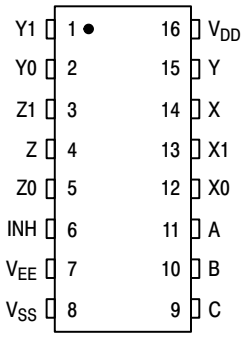
MC14051B



MC14052B



MC14053B



ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	V_{DD}	Test Conditions	– 55°C Min	– 55°C Max	25°C Min	25°C Typ (3.)	25°C Max	125°C Min	125°C Max	Unit
SUPPLY REQUIREMENTS (Voltages Referenced to V_{EE})											
Power Supply Voltage Range	V_{DD}	—	$V_{DD} – 3.0 \geq V_{SS} \geq V_{EE}$	3.0	18	3.0	—	18	3.0	18	V
Quiescent Current Per Package	I_{DD}	5.0 10 15	Control Inputs: $V_{in} = V_{SS}$ or V_{DD}, Switch I/O: $V_{EE} \leq V_{I/O} \leq V_{DD}$, and $\Delta V_{switch} \leq 500$ mV (4.)	— — —	5.0 10 20	— — —	0.005 0.010 0.015	5.0 10 20	— — —	150 300 600	μA
Total Supply Current (Dynamic Plus Quiescent, Per Package	$I_{D(AV)}$	5.0 10 15	$T_A = 25°C$ only (The channel component, $(V_{in} – V_{out})/R_{on}$, is not included.)	Typical			(0.07 μA/kHz) f + I_{DD} (0.20 μA/kHz) f + I_{DD} (0.36 μA/kHz) f + I_{DD}				μA
CONTROL INPUTS — INHIBIT, A, B, C (Voltages Referenced to V_{SS})											
Low–Level Input Voltage	V_{IL}	5.0 10 15	R_{on} = per spec, I_{off} = per spec	— — —	1.5 3.0 4.0	— — —	2.25 4.50 6.75	1.5 3.0 4.0	— — —	1.5 3.0 4.0	V
High–Level Input Voltage	V_{IH}	5.0 10 15	R_{on} = per spec, I_{off} = per spec	3.5 7.0 11	— — —	3.5 7.0 11	2.75 5.50 8.25	— — —	3.5 7.0 11	— — —	V
Input Leakage Current	I_{in}	15	V_{in} = 0 or V_{DD}	—	± 0.1	—	±0.00001	± 0.1	—	1.0	μA
Input Capacitance	C_{in}	—		—	—	—	5.0	7.5	—	—	pF
SWITCHES IN/OUT AND COMMONS OUT/IN — X, Y, Z (Voltages Referenced to V_{EE})											
Recommended Peak–to–Peak Voltage Into or Out of the Switch	$V_{I/O}$	—	Channel On or Off	0	V_{DD}	0	—	V_{DD}	0	V_{DD}	V_{PP}
Recommended Static or Dynamic Voltage Across the Switch (4.) (Figure 5)	ΔV_{switch}	—	Channel On	0	600	0	—	600	0	300	mV
Output Offset Voltage	V_{OO}	—	V_{in} = 0 V, No Load	—	—	—	10	—	—	—	μV
ON Resistance	R_{on}	5.0 10 15	$\Delta V_{switch} \leq 500$ mV (4.) $V_{in} = V_{IL}$ or V_{IH} (Control), and V_{in} = 0 to V_{DD} (Switch)	— — —	800 400 220	— — —	250 120 80	1050 500 280	— — —	1200 520 300	Ω
ΔON Resistance Between Any Two Channels in the Same Package	ΔR_{on}	5.0 10 15		— — —	70 50 45	— — —	25 10 10	70 50 45	— — —	135 95 65	Ω
Off–Channel Leakage Current (Figure 10)	I_{off}	15	$V_{in} = V_{IL}$ or V_{IH} (Control) Channel to Channel or Any One Channel	—	± 100	—	± 0.05	± 100	—	±1000	nA
Capacitance, Switch I/O	$C_{I/O}$	—	Inhibit = V_{DD}	—	—	—	10	—	—	—	pF
Capacitance, Common O/I	$C_{O/I}$	—	Inhibit = V_{DD} (MC14051B) (MC14052B) (MC14053B)	 — — —	 — — —	 — — —	 60 32 17	 — — —	 — — —	 — — —	pF
Capacitance, Feedthrough (Channel Off)	$C_{I/O}$	— —	Pins Not Adjacent Pins Adjacent	— —	— —	— —	0.15 0.47	— —	— —	— —	pF

3. Data labeled “Typ” is not to be used for design purposes, but is intended as an indication of the IC’s potential performance.
4. For voltage drops across the switch (ΔV_{switch}) > 600 mV (> 300 mV at high temperature), excessive V_{DD} current may be drawn, i.e. the current out of the switch may contain both V_{DD} and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded. (See first page of this data sheet.)

ELECTRICAL CHARACTERISTICS [5.] (C_L = 50 pF, T_A = 25°C) ($V_{EE} \le V_{SS}$ unless otherwise indicated)

Characteristic	Symbol	$V_{DD} - V_{EE}$ Vdc	Typ [6.] All Types	Max	Unit
Propagation Delay Times (Figure 6)	t_{PLH}, t_{PHL}				ns
Switch Input to Switch Output (R_L = 10 kΩ)					
MC14051					
t_{PLH}, t_{PHL} = (0.17 ns/pF) C_L + 26.5 ns		5.0	35	90	
t_{PLH}, t_{PHL} = (0.08 ns/pF) C_L + 11 ns		10	15	40	
t_{PLH}, t_{PHL} = (0.06 ns/pF) C_L + 9.0 ns		15	12	30	
MC14052					ns
t_{PLH}, t_{PHL} = (0.17 ns/pF) C_L + 21.5 ns		5.0	30	75	
t_{PLH}, t_{PHL} = (0.08 ns/pF) C_L + 8.0 ns		10	12	30	
t_{PLH}, t_{PHL} = (0.06 ns/pF) C_L + 7.0 ns		15	10	25	
MC14053					ns
t_{PLH}, t_{PHL} = (0.17 ns/pF) C_L + 16.5 ns		5.0	25	65	
t_{PLH}, t_{PHL} = (0.08 ns/pF) C_L + 4.0 ns		10	8.0	20	
t_{PLH}, t_{PHL} = (0.06 ns/pF) C_L + 3.0 ns		15	6.0	15	
Inhibit to Output (R_L = 10 kΩ, $V_{EE} = V_{SS}$) Output "1" or "0" to High Impedance, or High Impedance to "1" or "0" Level	t_{PHZ}, t_{PLZ}, t_{PZH}, t_{PZL}				ns
MC14051B		5.0	350	700	
		10	170	340	
		15	140	280	
MC14052B		5.0	300	600	ns
		10	155	310	
		15	125	250	
MC14053B		5.0	275	550	ns
		10	140	280	
		15	110	220	
Control Input to Output (R_L = 10 kΩ, $V_{EE} = V_{SS}$)	t_{PLH}, t_{PHL}				ns
MC14051B		5.0	360	720	
		10	160	320	
		15	120	240	
MC14052B		5.0	325	650	ns
		10	130	260	
		15	90	180	
MC14053B		5.0	300	600	ns
		10	120	240	
		15	80	160	
Second Harmonic Distortion (R_L = 10KΩ, f = 1 kHz) V_{in} = 5 V_{PP}	—	10	0.07	—	%
Bandwidth (Figure 7) (R_L = 1 kΩ, V_{in} = 1/2 (V_{DD}–V_{EE}) p–p, C_L = 50pF 20 Log (V_{out}/V_{in}) = – 3 dB)	BW	10	17	—	MHz
Off Channel Feedthrough Attenuation (Figure 7) R_L = 1KΩ, V_{in} = 1/2 (V_{DD} – V_{EE}) p–p f_{in} = 4.5 MHz — MC14051B f_{in} = 30 MHz — MC14052B f_{in} = 55 MHz — MC14053B	—	10	– 50	—	dB
Channel Separation (Figure 8) (R_L = 1 kΩ, V_{in} = 1/2 (V_{DD}–V_{EE}) p–p, f_{in} = 3.0 MHz	—	10	– 50	—	dB
Crosstalk, Control Input to Common O/I (Figure 9) (R_1 = 1 kΩ, R_L = 10 kΩ Control $t_{TLH} = t_{THL}$ = 20 ns, Inhibit = V_{SS})	—	10	75	—	mV

5. The formulas given are for the typical characteristics only at 25°C.
6. Data labelled "Typ" is not lo be used for design purposes but In intended as an indication of the IC's potential performance.

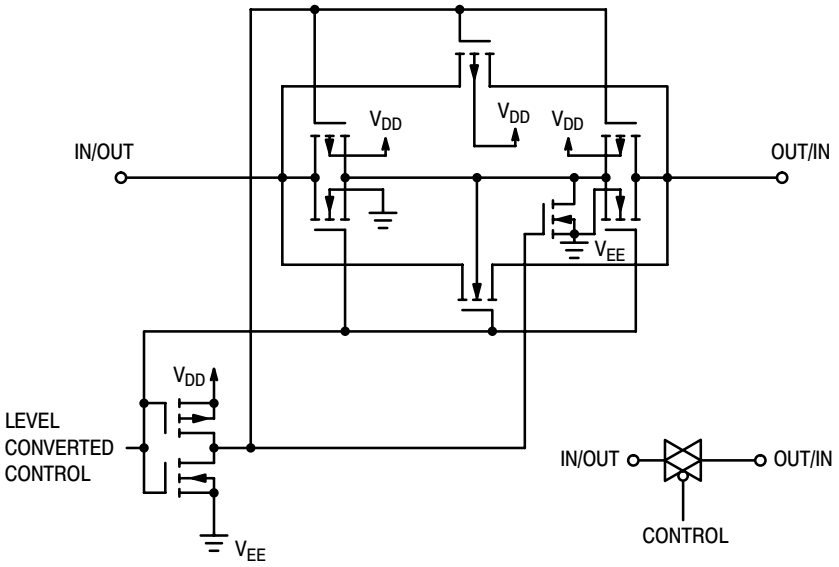


Figure 1. Switch Circuit Schematic

TRUTH TABLE

Control Inputs				ON Switches					
	Select								
Inhibit	C*	B	A	MC14051B	MC14052B		MC14053B		
0	0	0	0	X0	Y0	X0	Z0	Y0	X0
0	0	0	1	X1	Y1	X1	Z0	Y0	X1
0	0	1	0	X2	Y2	X2	Z0	Y1	X0
0	0	1	1	X3	Y3	X3	Z0	Y1	X1
0	1	0	0	X4			Z1	Y0	X0
0	1	0	1	X5			Z1	Y0	X1
0	1	1	0	X6			Z1	Y1	X0
0	1	1	1	X7			Z1	Y1	X1
1	x	x	x	None	None		None		

*Not applicable for MC14052
x = Don't Care

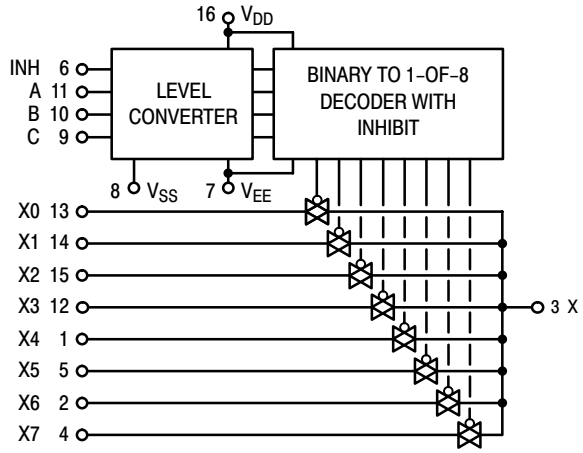


Figure 2. MC14051B Functional Diagram

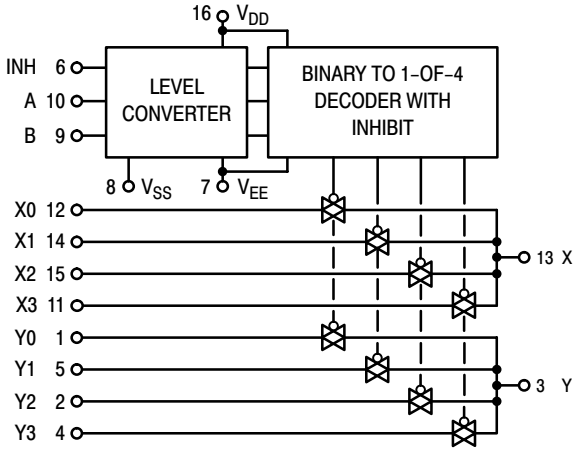


Figure 3. MC14052B Functional Diagram

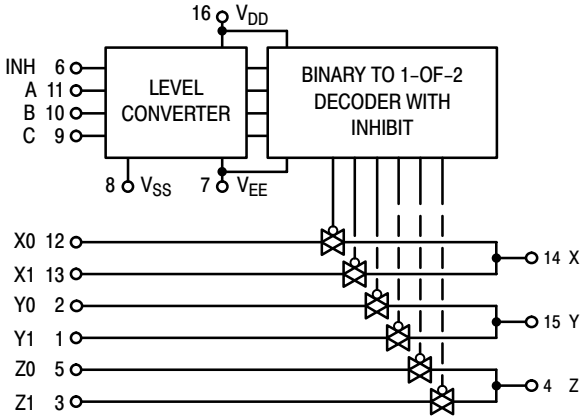


Figure 4. MC14053B Functional Diagram

TEST CIRCUITS

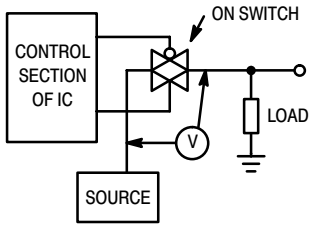


Figure 5. ΔV Across Switch

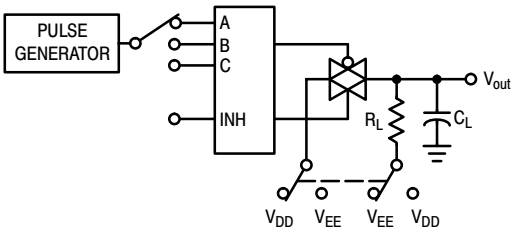


Figure 6. Propagation Delay Times, Control and Inhibit to Output

A, B, and C inputs used to turn ON or OFF
the switch under test.

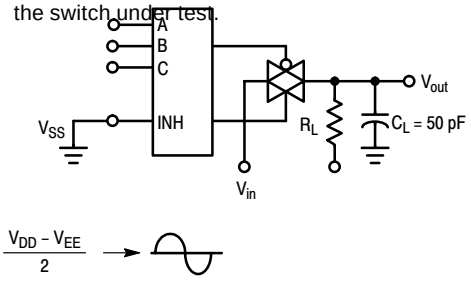


Figure 7. Bandwidth and Off–Channel Feedthrough Attenuation

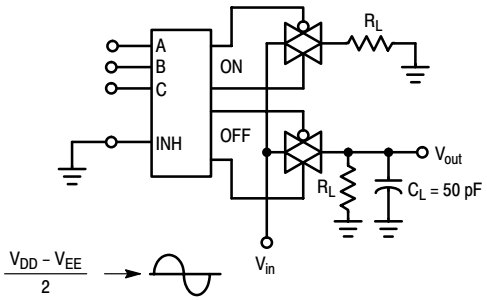


Figure 8. Channel Separation (Adjacent Channels Used For Setup)

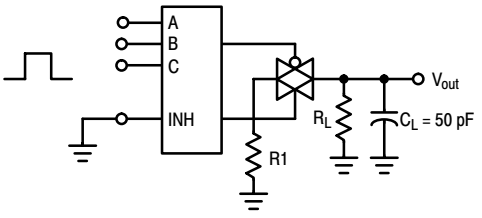


Figure 9. Crosstalk, Control Input to Common O/I

NOTE: See also Figures 7 and 8 in the MC14016B data sheet.

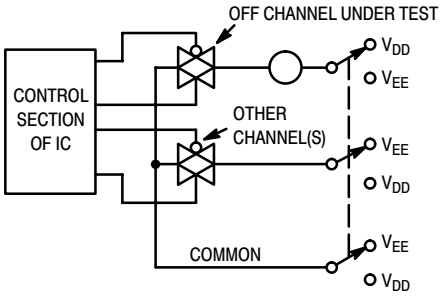


Figure 10. Off Channel Leakage

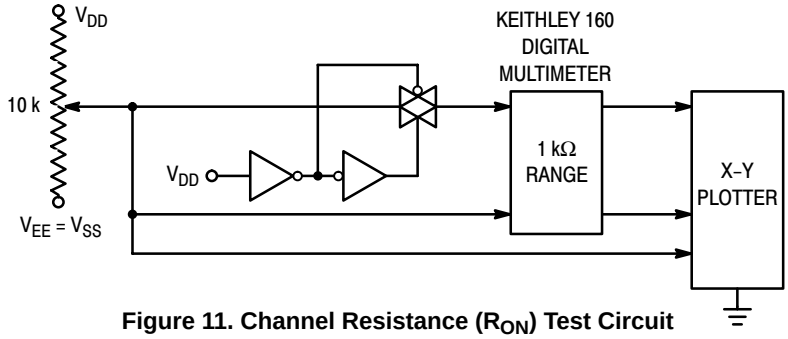


Figure 11. Channel Resistance (R_{ON}) Test Circuit

TYPICAL RESISTANCE CHARACTERISTICS

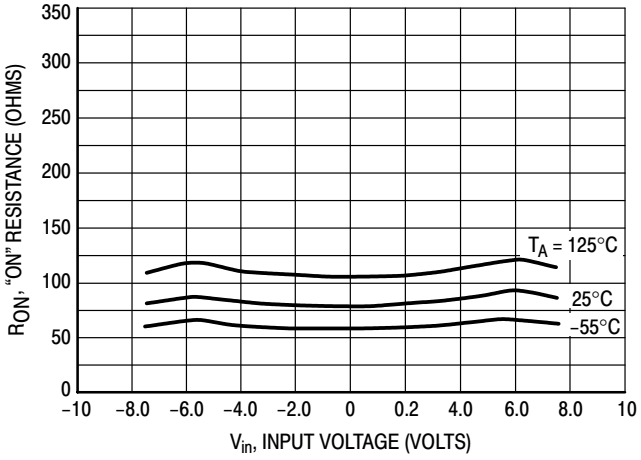


Figure 12. V_{DD} = 7.5 V, V_{EE} = – 7.5 V

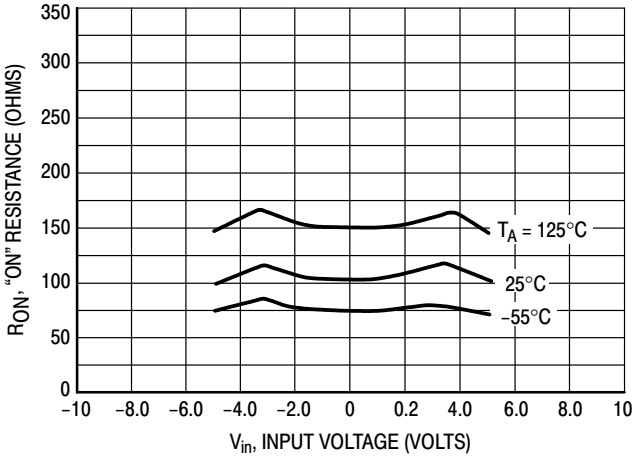


Figure 13. V_{DD} = 5.0 V, V_{EE} = – 5.0 V

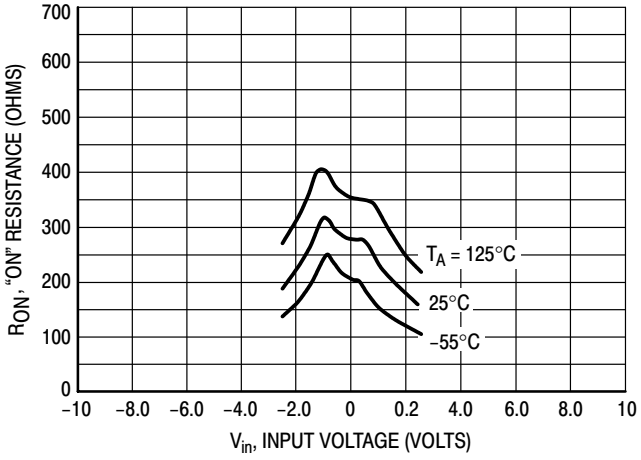


Figure 14. V_{DD} = 2.5 V, V_{EE} = – 2.5 V

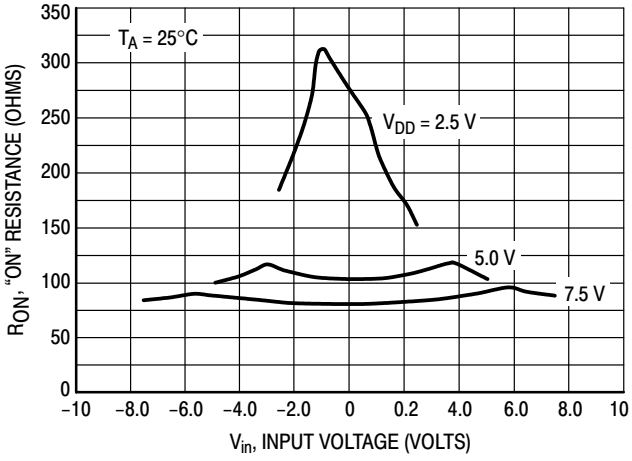


Figure 15. Comparison at 25°C, $V_{DD} = -V_{EE}$

APPLICATIONS INFORMATION

Figure A illustrates use of the on–chip level converter detailed in Figures 2, 3, and 4. The 0–to–5 V Digital Control signal is used to directly control a 9 V_{p-p} analog signal.

The digital control logic levels are determined by V_{DD} and V_{SS}. The V_{DD} voltage is the logic high voltage; the V_{SS} voltage is logic low. For the example, V_{DD} = + 5 V = logic high at the control inputs; V_{SS} = GND = 0 V = logic low.

The maximum analog signal level is determined by V_{DD} and V_{EE}. The V_{DD} voltage determines the maximum recommended peak above V_{SS}. The V_{EE} voltage determines the maximum swing below V_{SS}. For the example, $V_{DD} - V_{SS}$ = 5 V maximum swing above V_{SS}; $V_{SS} - V_{EE}$ = 5 V maximum swing below V_{SS}. The example shows a ± 4.5 V signal which allows a 1/2 volt margin at each peak. If voltage transients above V_{DD} and/or below V_{EE} are anticipated on the analog channels, external diodes (Dx) are recommended as shown in Figure B. These diodes should be small signal types able to absorb the maximum anticipated current surges during clipping.

The *absolute* maximum potential difference between V_{DD} and V_{EE} is 18.0 V. Most parameters are specified up to 15 V which is the *recommended* maximum difference between V_{DD} and V_{EE}.

Balanced supplies are not required. However, V_{SS} must be greater than or equal to V_{EE}. For example, V_{DD} = + 10 V, V_{SS} = + 5 V, and V_{EE} – 3 V is acceptable. See the Table below.

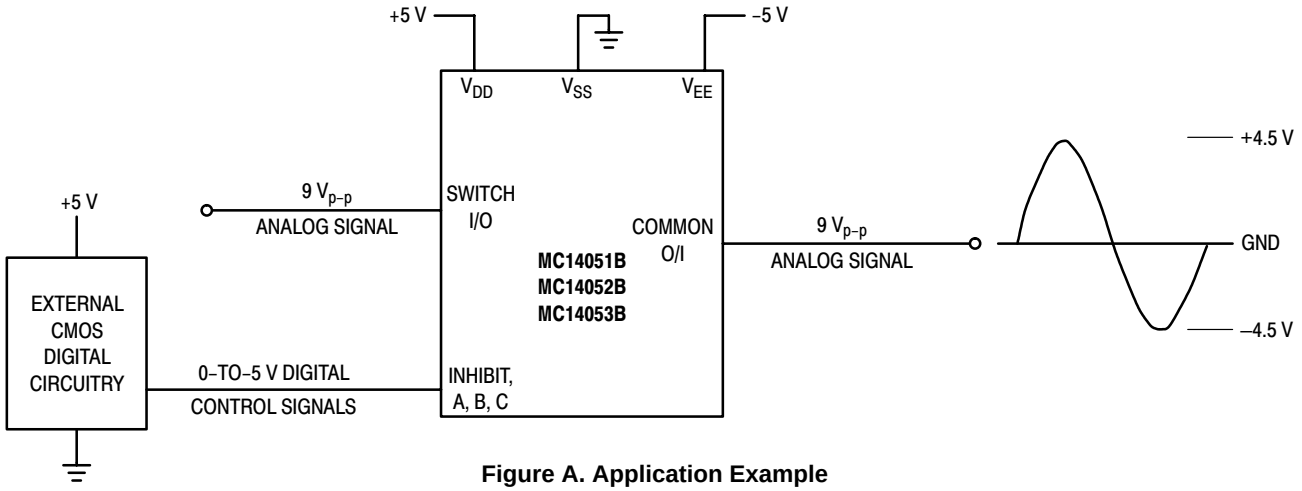


Figure A. Application Example

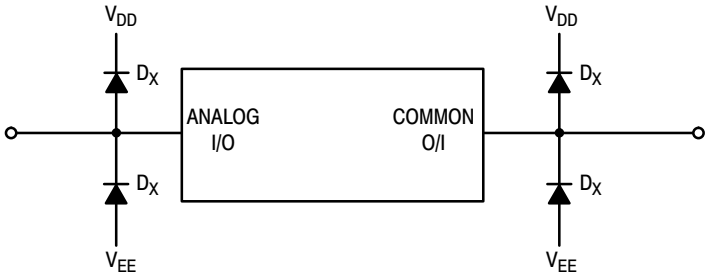


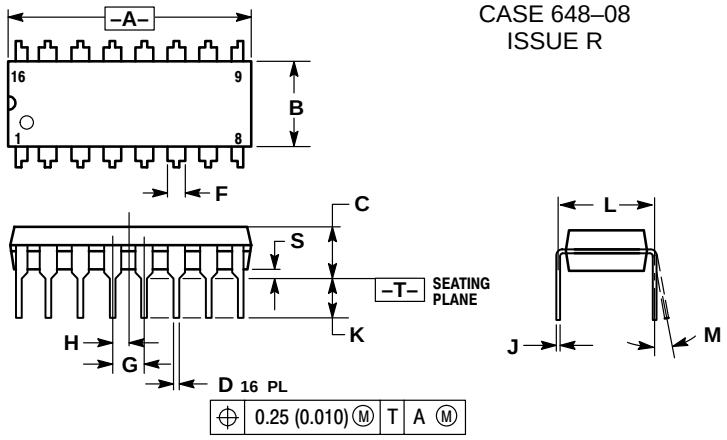
Figure B. External Germanium or Schottky Clipping Diodes

POSSIBLE SUPPLY CONNECTIONS

V_{DD} In Volts	V_{SS} In Volts	V_{EE} In Volts	Control Inputs Logic High/Logic Low In Volts	Maximum Analog Signal Range In Volts
+ 8	0	– 8	+ 8/0	+ 8 to – 8 = 16 V_{p-p}
+ 5	0	– 12	+ 5/0	+ 5 to – 12 = 17 V_{p-p}
+ 5	0	0	+ 5/0	+ 5 to 0 = 5 V_{p-p}
+ 5	0	– 5	+ 5/0	+ 5 to – 5 = 10 V_{p-p}
+ 10	+ 5	– 5	+ 10/ + 5	+ 10 to – 5 = 15 V_{p-p}

PACKAGE DIMENSIONS

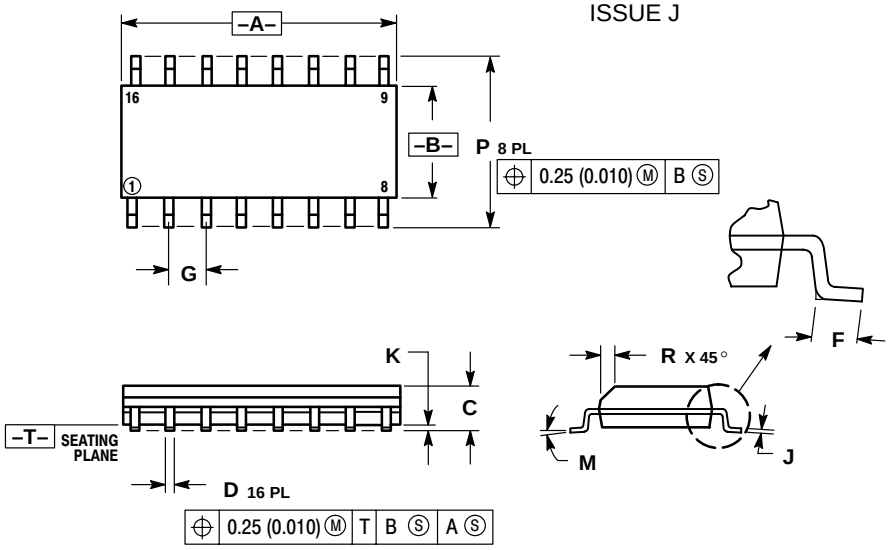
PDIP–16
P SUFFIX
PLASTIC DIP PACKAGE
CASE 648–08
ISSUE R



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0 °	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

SOIC–16
D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751B–05
ISSUE J

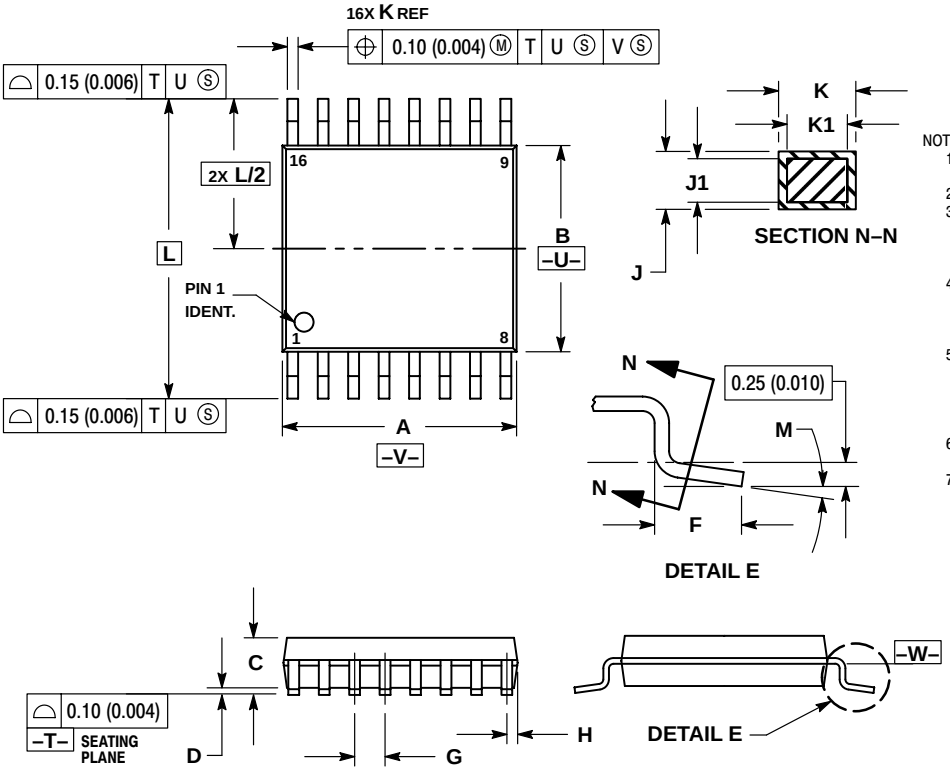


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

PACKAGE DIMENSIONS

TSSOP–16
DT SUFFIX
PLASTIC TSSOP PACKAGE
CASE 948F–01
ISSUE O

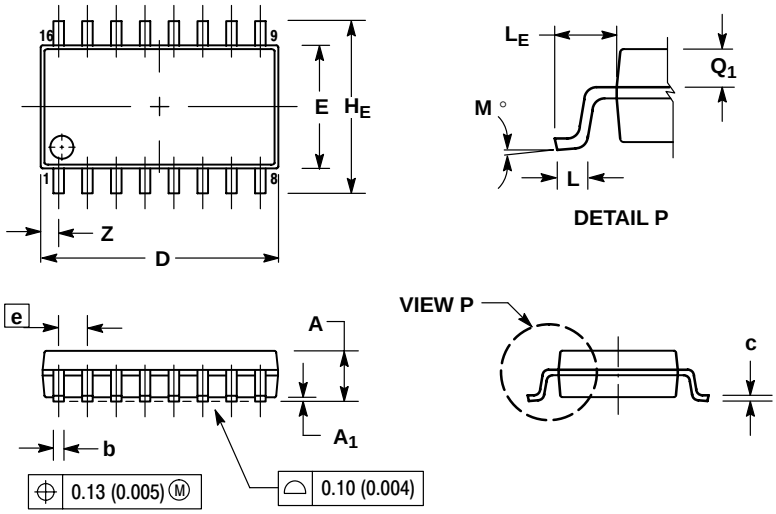


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

PACKAGE DIMENSIONS

SOEIAJ–16
F SUFFIX
PLASTIC EIAJ SOIC PACKAGE
CASE 966–01
ISSUE O



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A_1	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
H_E	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
L_E	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10 °
Q_1	0.70	0.90	0.028	0.035
Z	---	0.78	---	0.031

ORDERING & SHIPPING INFORMATION:

Device	Package	Shipping
MC14051BCP	PDIP–16	2000 Units per Box
MC14051BD	SOIC–16	48 Units per Rail
MC14051BDR2	SOIC–16	2500 Units / Tape & Reel
MC14051BDT	TSSOP–16	96 Units per Rail
MC14051BDTEL	TSSOP–16	2000 Units / Tape & Reel
MC14051BDTR2	TSSOP–16	2500 Units / Tape & Reel
MC14051BF	SOEIAJ–16	See Note 7.
MC14051BFEL	SOEIAJ–16	See Note 7.
MC14052BCP	PDIP–16	2000 Units per Box
MC14052BD	SOIC–16	48 Units per Rail
MC14052BDR2	SOIC–16	2500 Units / Tape & Reel
MC14052BDT	TSSOP–16	96 Units per Rail
MC14052BDTR2	TSSOP–16	2500 Units / Tape & Reel
MC14052BF	SOEIAJ–16	See Note 7.
MC14052BFEL	SOEIAJ–16	See Note 7.

ORDERING & SHIPPING INFORMATION:

MC14053BCP	PDIP–16	2000 Units per Box
MC14053BD	SOIC–16	48 Units per Rail
MC14053BDR2	SOIC–16	2500 Units / Tape & Reel
MC14053BDT	TSSOP–16	96 Units per Rail
MC14053BDTEL	TSSOP–16	2000 Units / Tape & Reel
MC14053BDTR2	TSSOP–16	2500 Units / Tape & Reel
MC14053BF	SOEIAJ–16	See Note 7.
MC14053BFEL	SOEIAJ–16	See Note 7.

7. For ordering information on the EIAJ version of the SOIC packages, please contact your local ON Semiconductor representative.

PUBLICATION ORDERING INFORMATION

NORTH AMERICA Literature Fulfillment:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada
Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada
Email: ONlit@hibbertco.com
Fax Response Line: 303–675–2167 or 800–344–3810 Toll Free USA/Canada

N. American Technical Support: 800–282–9855 Toll Free USA/Canada

EUROPE: LDC for ON Semiconductor – European Support
German Phone: (+1) 303–308–7140 (Mon–Fri 2:30pm to 7:00pm CET)
Email: ONlit–german@hibbertco.com
French Phone: (+1) 303–308–7141 (Mon–Fri 2:00pm to 7:00pm CET)
Email: ONlit–french@hibbertco.com
English Phone: (+1) 303–308–7142 (Mon–Fri 12:00pm to 5:00pm GMT)
Email: ONlit@hibbertco.com

EUROPEAN TOLL–FREE ACCESS*: 00–800–4422–3781
*Available from Germany, France, Italy, UK

CENTRAL/SOUTH AMERICA:
Spanish Phone: 303–308–7143 (Mon–Fri 8:00am to 5:00pm MST)
Email: ONlit–spanish@hibbertco.com

ASIA/PACIFIC: LDC for ON Semiconductor – Asia Support
Phone: 303–675–2121 (Tue–Fri 9:00am to 1:00pm, Hong Kong Time)
Toll Free from Hong Kong & Singapore:
001–800–4422–3781
Email: ONlit–asia@hibbertco.com

JAPAN: ON Semiconductor, Japan Customer Focus Center
4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan 141–0031
Phone: 81–3–5740–2745
Email: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local Sales Representative.